NSN 5961-01-154-6353

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View Online at https://aerobasegroup.com/nsn/5961-01-154-6353 **Inclosure Material:** Metal **Overall Length:** Between 0.150 inches and 0.180 inches Overall Diameter: Between 0.245 inches and 0.255 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage/static/emitter open and 30.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage, static, collector open **Power Rating Per Characteristic:** 5.8 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Test Data Document:** 03538-77a101066 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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